

### FEATURES

**High DC Precision**  
**100  $\mu\text{V}$  Max Offset Voltage**  
**1.5  $\mu\text{V}/^\circ\text{C}$  Max Offset Drift**  
**200 pA Max Input Bias Current**  
**0.5  $\mu\text{V}$  p-p Voltage Noise, 0.1 Hz to 10 Hz**  
**750  $\mu\text{A}$  Supply Current**  
**Available in 8-Lead Plastic Mini-DIP and Surface-Mount (SOIC) Packages**  
**Available in Tape and Reel in Accordance with EIA-481A Standard**  
**Quad Version: AD704**

### APPLICATIONS

**Low Frequency Active Filters**  
**Precision Instrumentation**  
**Precision Integrators**

### GENERAL DESCRIPTION

The AD706 is a dual, low power, bipolar op amp that has the low input bias current of a JFET amplifier, but which offers a significantly lower  $I_B$  drift over temperature. It utilizes superbeta bipolar input transistors to achieve picoampere input bias current levels (similar to FET input amplifiers at room temperature), while its  $I_B$  typically only increases by  $5\times$  at  $125^\circ\text{C}$  (unlike a JFET amp, for which  $I_B$  doubles every  $10^\circ\text{C}$  for a  $1000\times$  increase at  $125^\circ\text{C}$ ). The AD706 also achieves the microvolt offset voltage and low noise characteristics of a precision bipolar input amplifier.

Since it has  $< 200$  pA of bias current, the AD706 does not require the commonly used "balancing" resistor. Furthermore, the current noise is only  $50 \text{ fA}/\sqrt{\text{Hz}}$ , which makes this amplifier usable with very high source impedances. At  $600 \mu\text{A}$  max supply current (per amplifier), the AD706 is well suited for today's high density boards.

The AD706 is an excellent choice for use in low frequency active filters in 12-bit and 14-bit data acquisition systems, in precision instrumentation, and as a high quality integrator. The AD706 is internally compensated for unity gain and is available in five performance grades. The AD706J is rated over the commercial temperature range of  $0^\circ\text{C}$  to  $+70^\circ\text{C}$ . The AD706A is rated for the extended industrial temperature range of  $-40^\circ\text{C}$  to  $+85^\circ\text{C}$ .

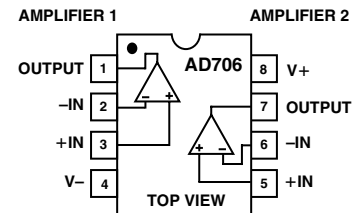
The AD706 is offered in two varieties of an 8-lead package: plastic mini-DIP and surface-mount (SOIC).

### REV. E

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### CONNECTION DIAGRAM

Plastic Mini-DIP (N) and Plastic SOIC (R) Packages



### PRODUCT HIGHLIGHTS

1. The AD706 is a dual low drift op amp that offers JFET level input bias currents, yet has the low  $I_B$  drift of a bipolar amplifier. It may be used in circuits using dual op amps such as the LT1024.
2. The AD706 provides both low drift and high dc precision.
3. The AD706 can be used in applications where a chopper amplifier would normally be required but without the chopper's inherent noise.

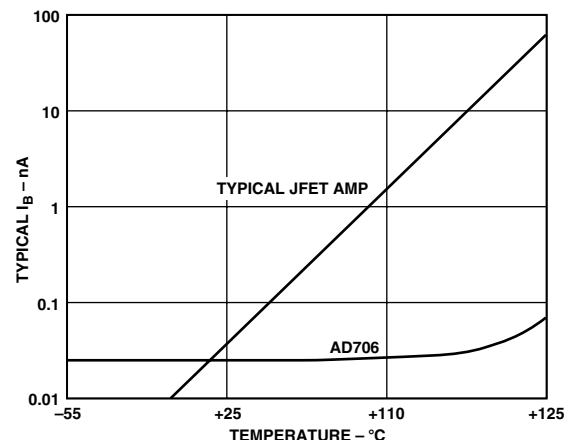


Figure 1. Input Bias Current vs. Temperature

# AD706—SPECIFICATIONS (@ T<sub>A</sub> = +25°C, V<sub>CM</sub> = 0 V and ±15 V dc, unless otherwise noted.)

Parameter	Conditions	AD706J/A			Unit
		Min	Typ	Max	
<b>INPUT OFFSET VOLTAGE</b>					
Initial Offset			30	100	μV
Offset	T <sub>MIN</sub> to T <sub>MAX</sub>		40	150	μV
vs. Temperature, Average TC			0.2	1.5	μV/°C
vs. Supply (PSRR)	V <sub>S</sub> = ±2 V to ±18 V	110	132		dB
T <sub>MIN</sub> to T <sub>MAX</sub>	V <sub>S</sub> = ±2.5 V to ±18 V	106	126		dB
Long Term Stability			0.3		μV/Month
<b>INPUT BIAS CURRENT<sup>1</sup></b>					
	V <sub>CM</sub> = 0 V		50	200	pA
	V <sub>CM</sub> = ±13.5 V			250	pA
vs. Temperature, Average TC			0.3		pA/°C
T <sub>MIN</sub> to T <sub>MAX</sub>	V <sub>CM</sub> = 0 V			300	pA
T <sub>MIN</sub> to T <sub>MAX</sub>	V <sub>CM</sub> = ±13.5 V			400	pA
<b>INPUT OFFSET CURRENT</b>					
	V <sub>CM</sub> = 0 V		30	150	pA
	V <sub>CM</sub> = ±13.5 V			250	pA
vs. Temperature, Average TC			0.6		pA/°C
T <sub>MIN</sub> to T <sub>MAX</sub>	V <sub>CM</sub> = 0 V		80	250	pA
T <sub>MIN</sub> to T <sub>MAX</sub>	V <sub>CM</sub> = ±13.5 V		80	350	pA
<b>MATCHING CHARACTERISTICS</b>					
Offset Voltage				150	μV
	T <sub>MIN</sub> to T <sub>MAX</sub>			250	μV
Input Bias Current <sup>2</sup>				300	pA
	T <sub>MIN</sub> to T <sub>MAX</sub>			500	pA
Common-Mode Rejection		106			dB
	T <sub>MIN</sub> to T <sub>MAX</sub>	106			dB
Power Supply Rejection		106			dB
	T <sub>MIN</sub> to T <sub>MAX</sub>	104			dB
Crosstalk (Figure 2a)	T <sub>MIN</sub> to T <sub>MAX</sub> @ f = 10 Hz R <sub>L</sub> = 2 kΩ		150		dB
<b>FREQUENCY RESPONSE</b>					
Unity Gain Crossover Frequency			0.8		MHz
Slew Rate	G = -1		0.15		V/μs
	T <sub>MIN</sub> to T <sub>MAX</sub>		0.15		V/μs
<b>INPUT IMPEDANCE</b>					
Differential			40  2		MΩ  pF
Common Mode			300  2		GΩ  pF
<b>INPUT VOLTAGE RANGE</b>					
Common-Mode Voltage		±13.5	±14		V
Common-Mode Rejection Ratio	V <sub>CM</sub> = ±13.5 V	110	132		dB
	T <sub>MIN</sub> to T <sub>MAX</sub>	108	128		dB
<b>INPUT CURRENT NOISE</b>					
	0.1 Hz to 10 Hz		3		pA p-p
	f = 10 Hz		50		fA/√Hz
<b>INPUT VOLTAGE NOISE</b>					
	0.1 Hz to 10 Hz		0.5		μV p-p
	f = 10 Hz		17		nV/√Hz
	f = 1 kHz		15	22	nV/√Hz
<b>OPEN-LOOP GAIN</b>					
	V <sub>O</sub> = ±12 V				V/mV
	R <sub>LOAD</sub> = 10 kΩ	200	2000		V/mV
	T <sub>MIN</sub> to T <sub>MAX</sub>	150	1500		V/mV
	V <sub>O</sub> = ±10 V				V/mV
	R <sub>LOAD</sub> = 2 kΩ	200	1000		V/mV
	T <sub>MIN</sub> to T <sub>MAX</sub>	150	1000		V/mV
<b>OUTPUT CHARACTERISTICS</b>					
Voltage Swing	R <sub>LOAD</sub> = 10 kΩ	±13	±14		V
	T <sub>MIN</sub> to T <sub>MAX</sub>	±13	±14		V
Current	Short Circuit		±15		mA
Capacitive Load Drive Capability	Gain = +1		10,000		pF

# SPECIFICATIONS (continued)

Parameter	Conditions	AD706J/A			Unit
		Min	Typ	Max	
POWER SUPPLY					
Rated Performance			±15		V
Operating Range		±2.0		±18	V
Quiescent Current, Total			0.75	1.2	mA
	T <sub>MIN</sub> to T <sub>MAX</sub>		0.8	1.4	mA
TRANSISTOR COUNT	Number of Transistors		90		

## NOTES

<sup>1</sup>Bias current specifications are guaranteed maximum at either input.

<sup>2</sup>Input bias current match is the difference between corresponding inputs (I<sub>B</sub> of -IN of Amplifier 1 minus I<sub>B</sub> of -IN of Amplifier 2).

CMRR match is the difference between  $\frac{\Delta V_{OS1}}{\Delta V_{CM}}$  for Amplifier 1 and  $\frac{\Delta V_{OS2}}{\Delta V_{CM}}$  for Amplifier 2, expressed in dB.

PSRR match is the difference between  $\frac{\Delta V_{OS1}}{\Delta V_{SUPPLY}}$  for Amplifier 1 and  $\frac{\Delta V_{OS2}}{\Delta V_{SUPPLY}}$  for Amplifier 2, expressed in dB.

All min and max specifications are guaranteed.  
Specifications subject to change without notice.

## ABSOLUTE MAXIMUM RATINGS<sup>1</sup>

Supply Voltage	±18 V
Internal Power Dissipation (Total: Both Amplifiers) <sup>2</sup>	650 mW
Input Voltage	±V <sub>S</sub>
Differential Input Voltage <sup>3</sup>	+0.7 V
Output Short Circuit Duration	Indefinite
Storage Temperature Range (N, R)	-65°C to +125°C
Operating Temperature Range	
AD706J	0°C to +70°C
AD706A	-40°C to +85°C
Lead Temperature (Soldering 10 secs)	300°C

## NOTES

<sup>1</sup>Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

<sup>2</sup>Specification is for device in free air:

8-Lead Plastic Package: θ<sub>JA</sub> = 100°C/W

8-Lead Small Outline Package: θ<sub>JA</sub> = 155°C/W

<sup>3</sup>The input pins of this amplifier are protected by back-to-back diodes. If the differential voltage exceeds ±0.7 V, external series protection resistors should be added to limit the input current to less than 25 mA.

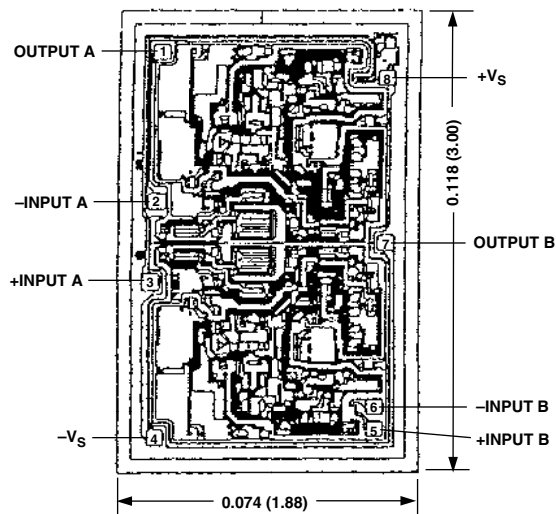
## ORDERING GUIDE

Model	Temperature Range	Description	Package Option
AD706JN	0°C to 70°C	Plastic DIP	N-8
AD706JR	0°C to 70°C	SOIC	R-8
AD706JR-REEL	0°C to 70°C	Tape and Reel	R-8
AD706JR-REEL7	0°C to 70°C	Tape and Reel	R-8
AD706AR	-40°C to +85°C	SOIC	R-8
AD706AR-REEL	-40°C to +85°C	Tape and Reel	R-8
AD706AR-REEL7	-40°C to +85°C	Tape and Reel	R-8
AD706ARZ-REEL*	-40°C to +85°C	Tape and Reel	R-8

\*Lead-free part.

## METALIZATION PHOTOGRAPH

Dimensions shown in inches and (mm).  
Contact factory for latest dimensions.



## CAUTION

ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 4000 V readily accumulate on the human body and test equipment and can discharge without detection. Although the AD706 features proprietary ESD protection circuitry, permanent damage may occur on devices subjected to high energy electrostatic discharges. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality.



# AD706—Typical Performance Characteristics

(Default Conditions:  $\pm 5\text{ V}$ ,  $C_L = 5\text{ pF}$ ,  $G = 2$ ,  $R_g = R_f = 1\text{ k}\Omega$ ,  $R_L = 2\text{ k}\Omega$ ,  $V_O = 2\text{ V p-p}$ , Frequency =  $1\text{ MHz}$ ,  $T_A = 25^\circ\text{C}$ )



TPC 1. Typical Distribution of Input Offset Voltage



TPC 2. Typical Distribution of Input Bias Current



TPC 3. Typical Distribution of Input Offset Current



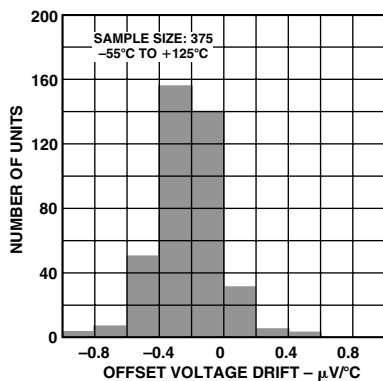
TPC 4. Input Common-Mode Voltage Range vs. Supply Voltage



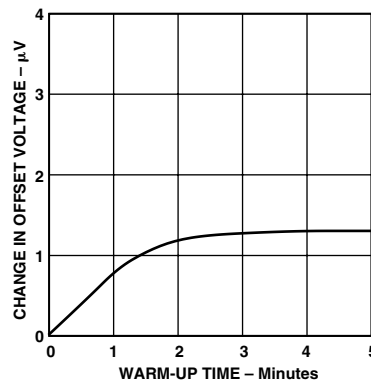
TPC 5. Large Signal Frequency Response



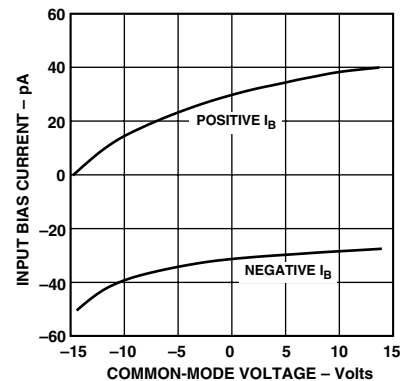
TPC 6. Offset Voltage Drift vs. Source Resistance



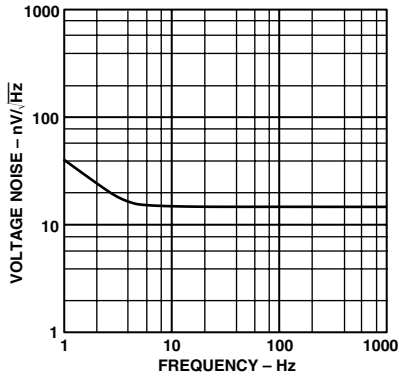
TPC 7. Typical Distribution of Offset Voltage Drift



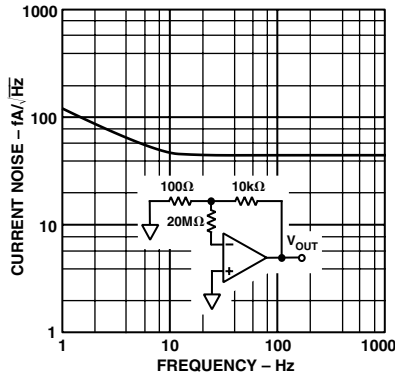
TPC 8. Change in Input Offset Voltage vs. Warm-Up Time



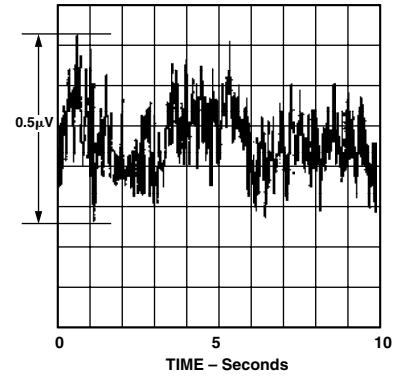
TPC 9. Input Bias Current vs. Common-Mode Voltage



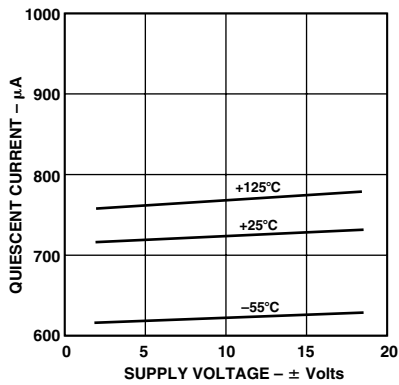
TPC 10. Input Noise Voltage Spectral Density



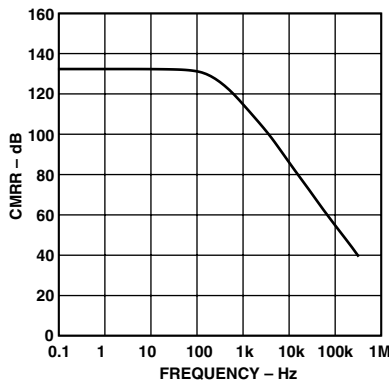
TPC 11. Input Noise Current Spectral Density



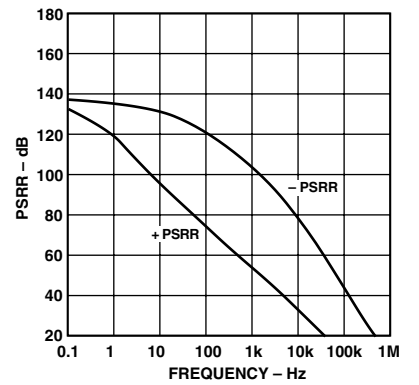
TPC 12. 0.1 Hz to 10 Hz Noise Voltage



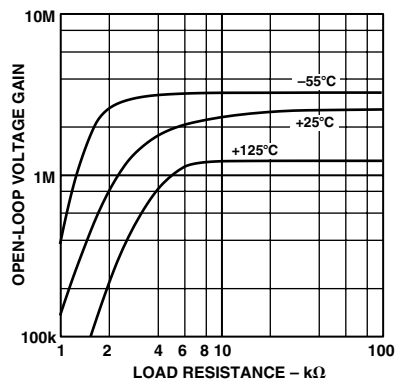
TPC 13. Quiescent Supply Current vs. Supply Voltage



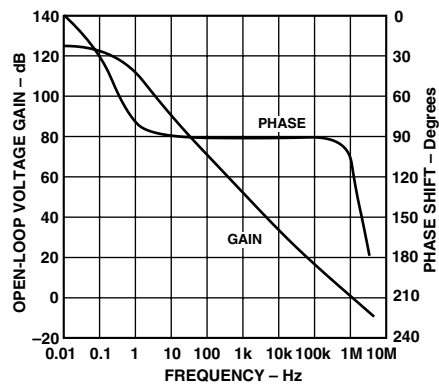
TPC 14. Common-Mode Rejection Ratio vs. Frequency



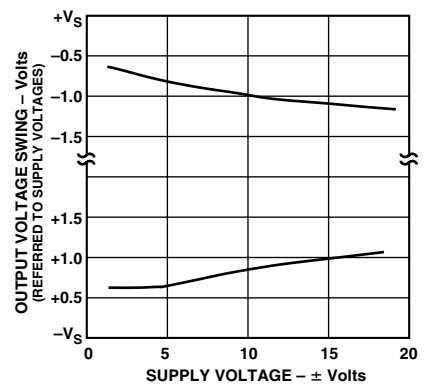
TPC 15. Power Supply Rejection Ratio vs. Frequency



TPC 16. Open-Loop Gain vs. Load Resistance vs. Load Resistance



TPC 17. Open-Loop Gain and Phase Shift vs. Frequency



TPC 18. Output Voltage Swing vs. Supply Voltage

# AD706

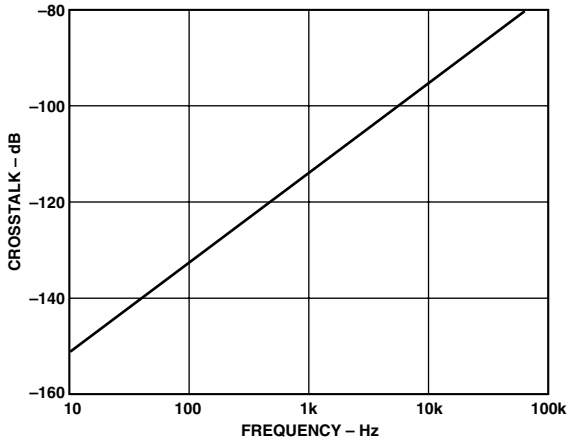


Figure 2a. Crosstalk vs. Frequency



Figure 3. Magnitude of Closed-Loop Output Impedance vs. Frequency

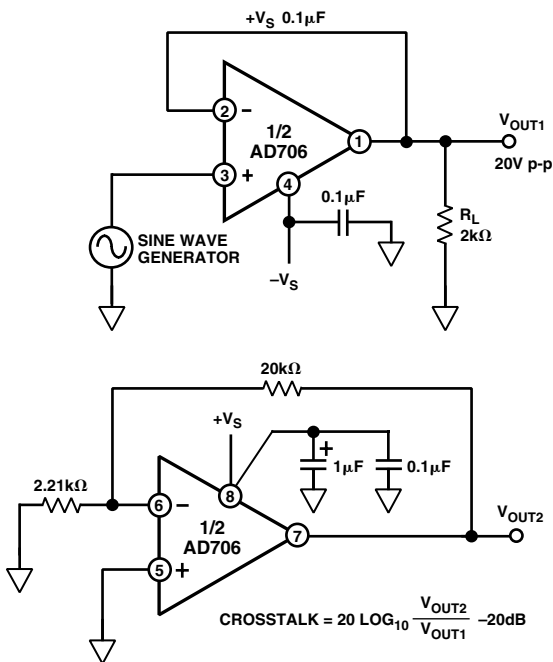


Figure 2b. Crosstalk Test Circuit

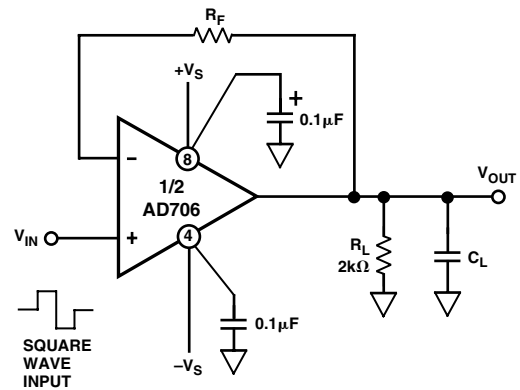


Figure 4a. Unity Gain Follower (For large signal applications, resistor  $R_F$  limits the current through the input protection diodes.)



Figure 4b. Unity Gain Follower Large Signal Pulse Response,  $R_F = 10 \text{ k}\Omega$ ,  $C_L = 1,000 \text{ pF}$



Figure 4c. Unity Gain Follower Small Signal Pulse Response,  $R_F = 0 \Omega$ ,  $C_L = 100 \text{ pF}$



Figure 4d. Unity Gain Follower Small Signal Pulse Response,  $R_F = 0 \Omega$ ,  $C_L = 1000 \text{ pF}$

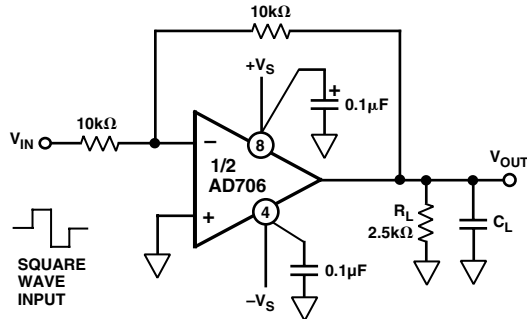


Figure 5a. Unity Gain Inverter Connection

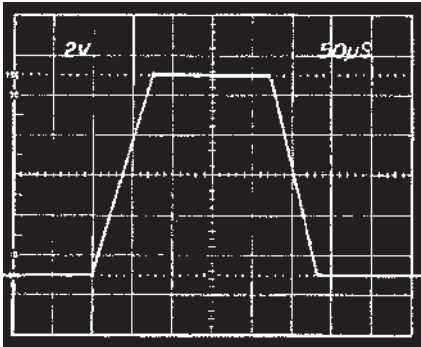


Figure 5b. Unity Gain Inverter Large Signal Pulse Response,  $C_L = 1,000 \text{ pF}$

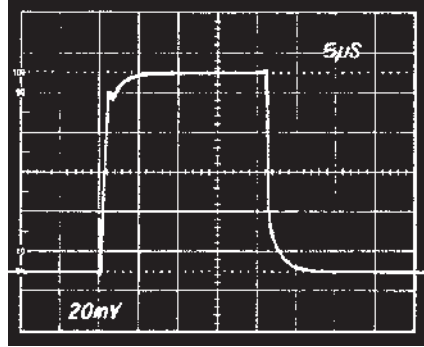


Figure 5c. Unity Gain Inverter Small Signal Pulse Response,  $C_L = 100 \text{ pF}$

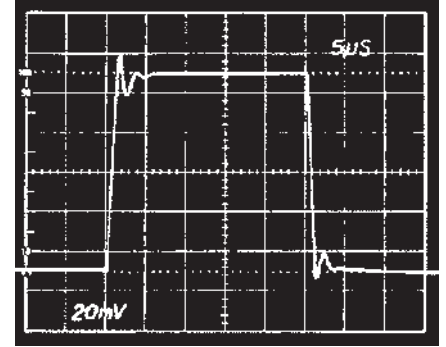


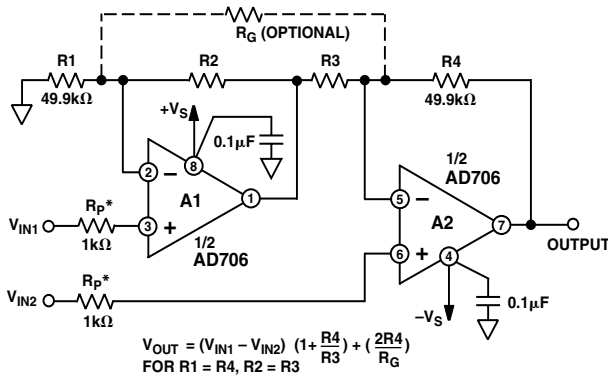
Figure 5d. Unity Gain Inverter Small Signal Pulse Response,  $C_L = 1000 \text{ pF}$

Figure 6 shows an in-amp circuit that has the obvious advantage of requiring only one AD706, rather than three op amps, with subsequent savings in cost and power consumption. The transfer function of this circuit (without  $R_G$ ) is

$$V_{OUT} = (V_{IN1} - V_{IN2}) \left( 1 + \frac{R4}{R3} \right)$$

for  $R1 = R4$  and  $R2 = R3$ .

Input resistance is high, thus permitting the signal source to have an unbalanced output impedance.



$$V_{OUT} = (V_{IN1} - V_{IN2}) \left( 1 + \frac{R4}{R3} \right) + \left( \frac{2R4}{R_G} \right)$$

FOR  $R1 = R4, R2 = R3$

\*OPTIONAL INPUT PROTECTION RESISTOR FOR GAINS GREATER THAN 100 OR INPUT VOLTAGES EXCEEDING THE SUPPLY VOLTAGE.

Figure 6. Two Op Amp Instrumentation Amplifier

Furthermore, the circuit gain may be fine trimmed using an optional trim resistor,  $R_G$ . Like the three op amp circuit, CMR increases with gain, once initial trimming is accomplished—but

CMR is still dependent upon the ratio matching of Resistors  $R1$  through  $R4$ . Resistor values for this circuit, using the optional gain resistor,  $R_G$ , can be calculated using

$$R1 = R4 = 49.9 \text{ k}\Omega$$

$$R2 = R3 = \frac{49.9 \text{ k}\Omega}{0.9G - 1}$$

$$R_G = \frac{99.8 \text{ k}\Omega}{0.06G}$$

where  $G$  = The desired circuit gain.

Table I provides practical 1% resistance values. Note that without resistor  $R_G$ ,  $R2$  and  $R3 = 49.9 \text{ k}\Omega / G - 1$ .

Table I. Operating Gains of Amplifiers A1 and A2 and Practical 1% Resistor Values for the Circuit of Figure 6

Circuit Gain	Gain of A1	Gain of A2	R2, R3	R1, R4
1.10	11.00	1.10	499 kΩ	49.9 kΩ
1.33	4.01	1.33	150 kΩ	49.9 kΩ
1.50	3.00	1.50	100 kΩ	49.9 kΩ
2.00	2.00	2.00	49.9 kΩ	49.9 kΩ
10.1	1.11	10.10	5.49 kΩ	49.9 kΩ
101.0	1.01	101.0	499 Ω	49.9 kΩ
1001	1.001	1001	49.9 Ω	49.9 kΩ

For a much more comprehensive discussion of in-amp applications, refer to the *Instrumentation Amplifier Applications Guide*—available free from Analog Devices, Inc.

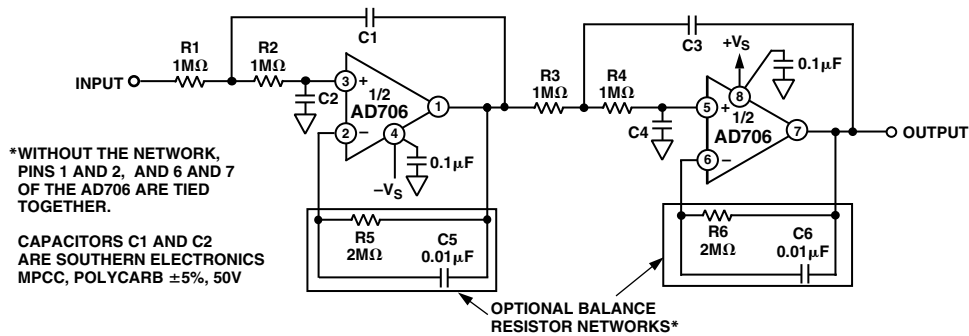


Figure 7. 1 Hz, 4-Pole Active Filter

### 1 Hz, 4-Pole, Active Filter

Figure 7 shows the AD706 in an active filter application. An important characteristic of the AD706 is that both the input bias current, input offset current, and their drift remain low over most of the op amp's rated temperature range. Therefore, for most applications, there is no need to use the normal balancing resistor. Adding the balancing resistor enhances performance at high temperatures, as shown by Figure 8.

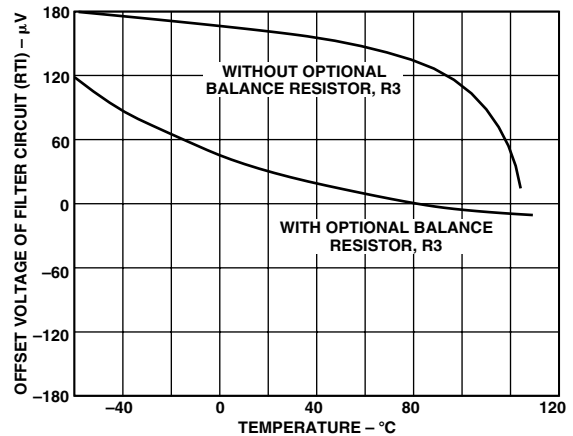


Figure 8.  $V_{OS}$  vs. Temperature Performance of the 1 Hz Filter

Table II. 1 Hz, 4-Pole, Low Pass Filter Recommended Component Values

Desired Low Pass Response	Section 1		Section 2		C1 (μF)	C2 (μF)	C3 (μF)	C4 (μF)
	Frequency (Hz)	Q	Frequency (Hz)	Q				
Bessel	1.43	0.522	1.60	0.806	0.116	0.107	0.160	0.0616
Butterworth	1.00	0.541	1.00	1.31	0.172	0.147	0.416	0.0609
0.1 dB Chebychev	0.648	0.619	0.948	2.18	0.304	0.198	0.733	0.0385
0.2 dB Chebychev	0.603	0.646	0.941	2.44	0.341	0.204	0.823	0.0347
0.5 dB Chebychev	0.540	0.705	0.932	2.94	0.416	0.209	1.00	0.0290
1.0 dB Chebychev	0.492	0.785	0.925	3.56	0.508	0.206	1.23	0.0242

NOTE

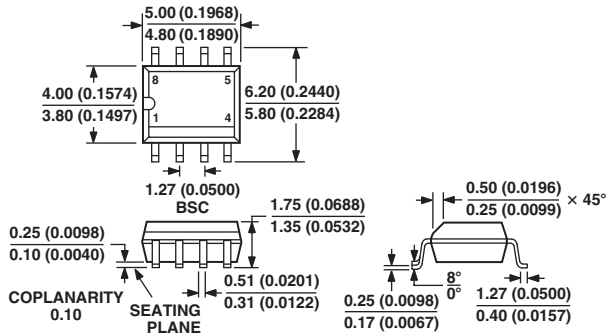
Specified Values are for a -3 dB point of 1.0 Hz. For other frequencies simply scale capacitors C1 through C4 directly, i.e. for 3 Hz Bessel response, C1 = 0.0387 μF, C2 = 0.0357 μF, C3 = 0.0533 μF, C4 = 0.0205 μF.



OUTLINE DIMENSIONS

8-Lead Standard Small Outline Package [SOIC]  
(R-8)

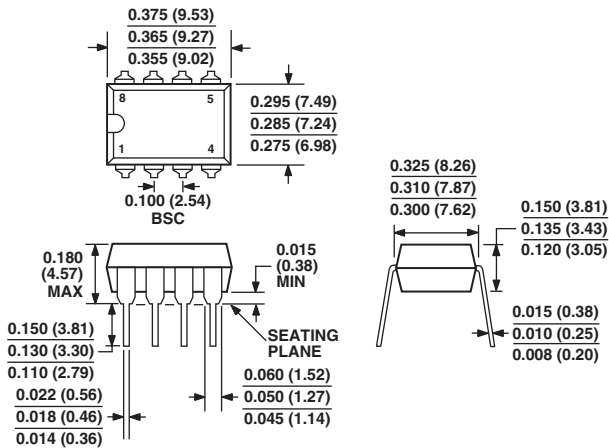
Dimensions shown in millimeters and (inches)



COMPLIANT TO JEDEC STANDARDS MS-012AA  
CONTROLLING DIMENSIONS ARE IN MILLIMETERS; INCH DIMENSIONS (IN PARENTHESES) ARE ROUNDED-OFF MILLIMETER EQUIVALENTS FOR REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN

8-Lead Plastic Dual-in-Line Package [PDIP]  
(N-8)

Dimensions shown in inches and (millimeters)



COMPLIANT TO JEDEC STANDARDS MO-095AA  
CONTROLLING DIMENSIONS ARE IN INCHES; MILLIMETER DIMENSIONS (IN PARENTHESES) ARE ROUNDED-OFF INCH EQUIVALENTS FOR REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN

# AD706

## Revision History

<b>Location</b>	<b>Page</b>
<b>10/03–Data Sheet changed from REV. D to REV. E</b>	
Removed the K Version .....	Universal
Updated FEATURES list .....	1
Updated PRODUCT DESCRIPTION .....	1
Renumbered TPCs .....	4
Renumbered Figures .....	6
Updated OUTLINE DIMENSIONS .....	9
<b>10/02–Data Sheet changed from REV. C to REV. D</b>	
Deleted 8-Lead CERDIP (Q-8) Package .....	Universal
Edits to FEATURES .....	1
Edits to PRODUCT DESCRIPTION .....	1
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Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



#### Как с нами связаться

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